Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-171-7675

| Inclosure Material: |
|--|
| Glass |
| Overall Length: |
| 0.300 inches |
| Terminal Length: |
| 1.000 inches |
| Overall Diameter: |
| 0.107 inches |
| Mounting Method: |
| Terminal |
| Features Provided: |
| Hermetically sealed case |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 75.0 reverse voltage, peak |
| Current Rating Per Characteristic: |
| 10.00 milliamperes source cutoff current preset |
| Capacitance Rating In Picofarads: |
| 4.0 |
| Maximum Operating Tempurature Per Measurement Point: |
| 175.0 degrees celsius ambient air |
| Terminal Type And Quantity: |
| 2 uninsulated wire lead |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
| |